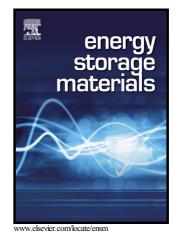
## Author's Accepted Manuscript

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## Abundant nanoscale defects to eliminate voltage decay in Li-rich cathode materials

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## Abstract

Li-rich layered oxides are promising high energy-density cathode, but will gradually become defective during cycling, thus suffer detrimental voltage decay. For countering these challenges, here we incorporate abundant nanoscale defects into materials' lattices to construct a bulk-modified

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